Hiroaki YANAGITA et al.
SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 1 of 7

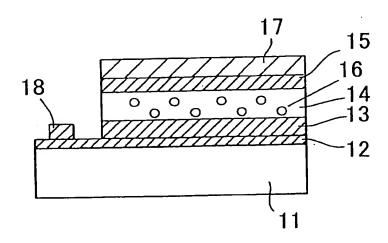
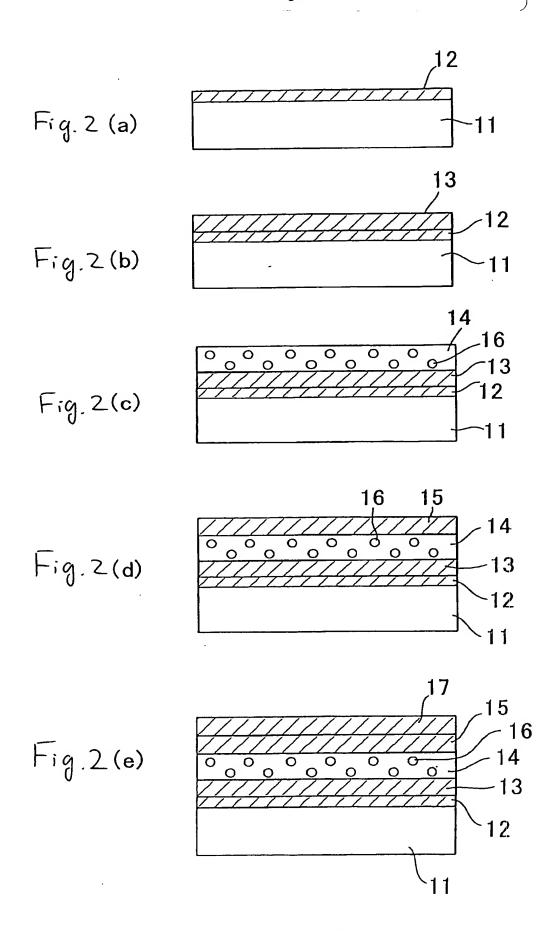


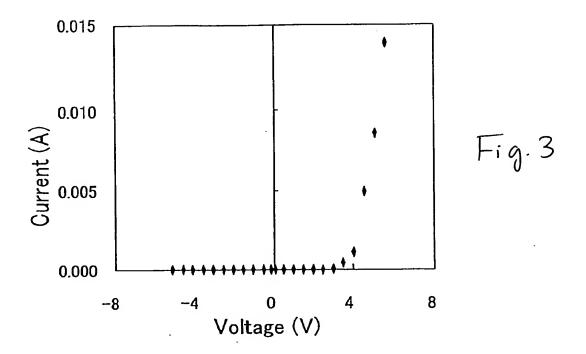
Fig. 1

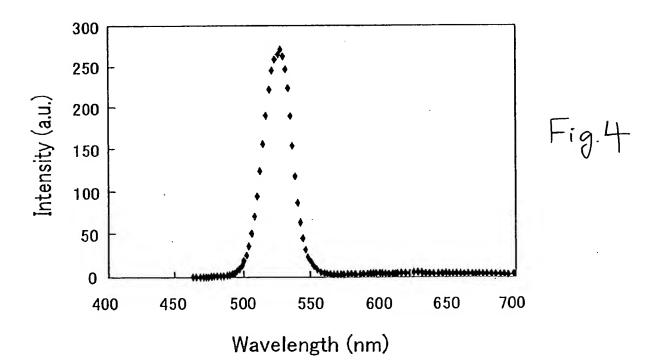
Hiroaki YANAGITA et al.
SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 2 of 7



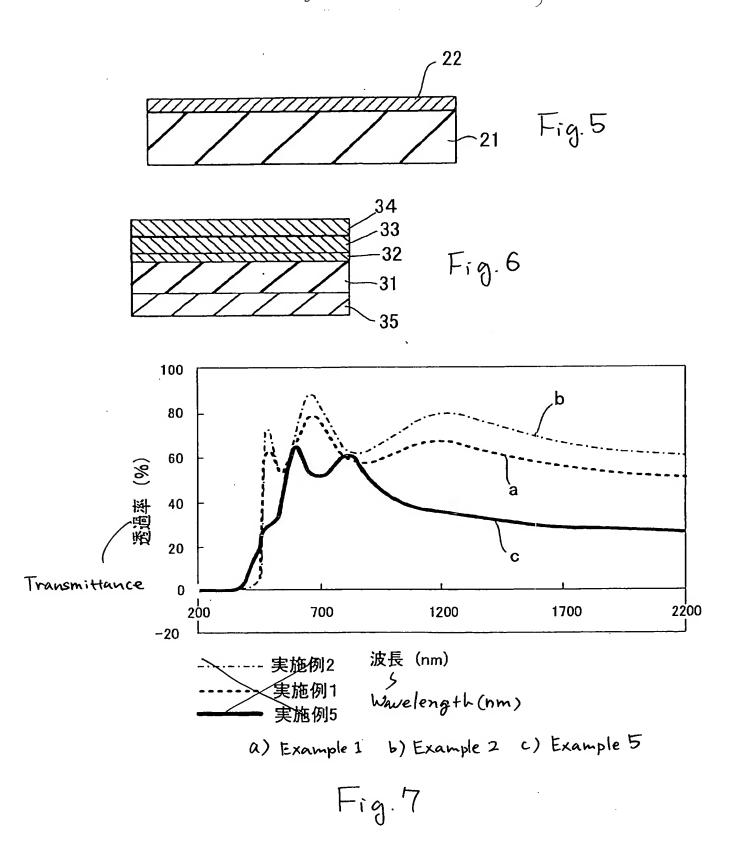
Hiroaki YANAGITA et al.

SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 3 of 7





Hiroaki YANAGITA et al.
SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 4 of 7



4/7

Hiroaki YANAGITA et al.

SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 5 of 7

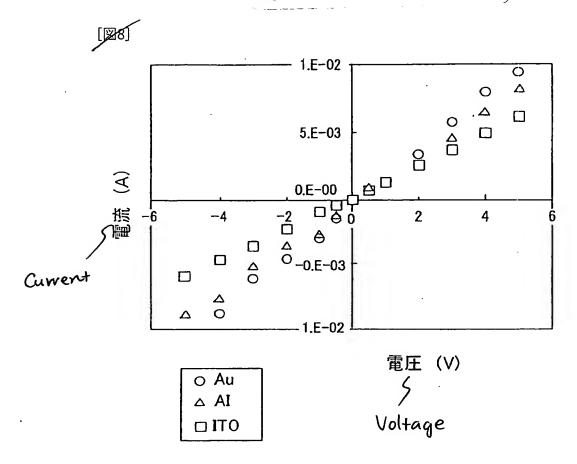


Fig.8

Hiroaki YANAGITA et al.
SEMICONDUCTOR MATERIAL AND
SEMICONDUCTOR DEVICE USING THE SAME
August 7, 2006
Darryl Mexic 202-293-7060
Q96380
Page 6 of 7

